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Inclosure Material:

Metal

Overall Length:

0.225 inches

Overall Diameter:

0.358 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 collector to emitter voltage, dc with base short-circuited to emitter and 30.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

4.00 amperes source cutoff current

Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

05896-723084 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0